

RELAY DRIVERS, LAMP DRIVERS,  
MOTOR DRIVERS AND STROBES APPLICATION.

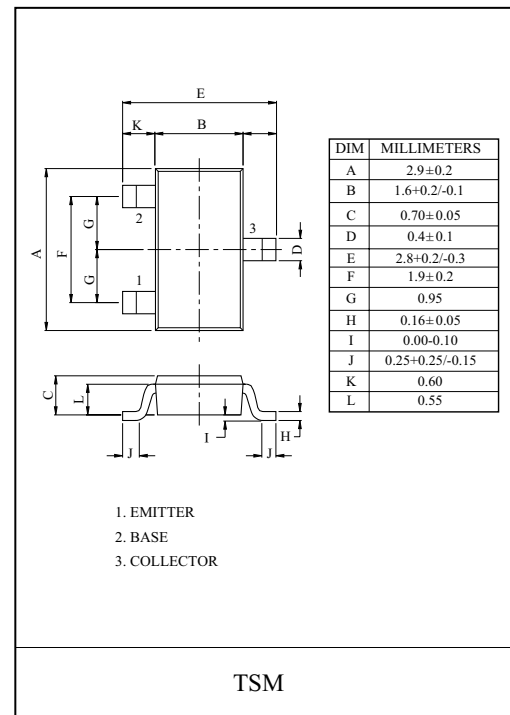
### FEATURES

- Adoption of MBIT Processes.
- Large Current Capacitance.
- Low Collector-to-Emitter Saturation Voltage.
- High Speed Switching.
- Ultrasmall Package facilitates miniaturization in end products.
- High Allowable Power Dissipation.
- Complementary to KTA1544T.

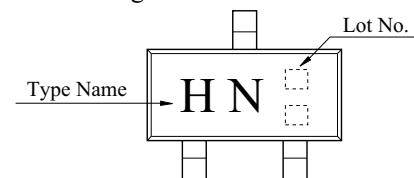
### MAXIMUM RATING (Ta=25 °C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$V_{CB0}$	30	V
Collector-Emitter Voltage	$V_{CEO}$	30	V
Emitter-Base Voltage	$V_{EBO}$	6	V
Collector Current	DC	$I_C$	A
	Pulse	$I_{CP}$	
Base Current	$I_B$	400	mA
Collector Power Dissipation	$P_C^*$	0.9	W
Junction Temperature	$T_j$	150	°C
Storage Temperature Range	$T_{stg}$	-55 ~ 150	°C

\* Package mounted on a ceramic board (600mm<sup>2</sup> × 0.8mm)



### Marking

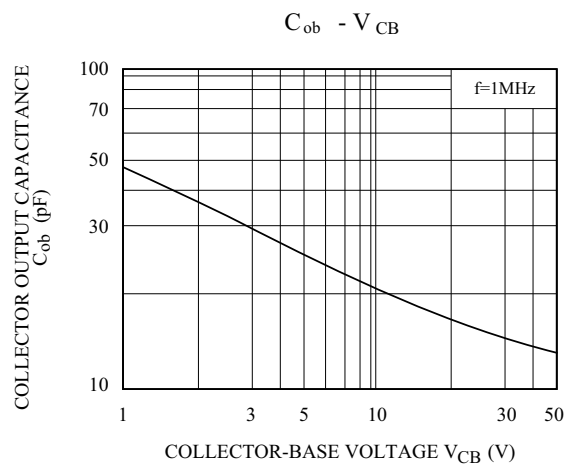
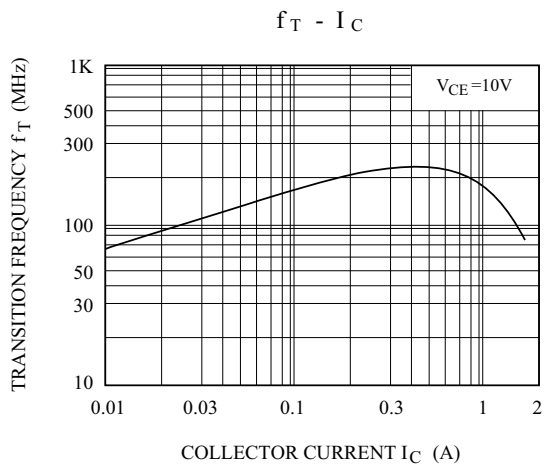
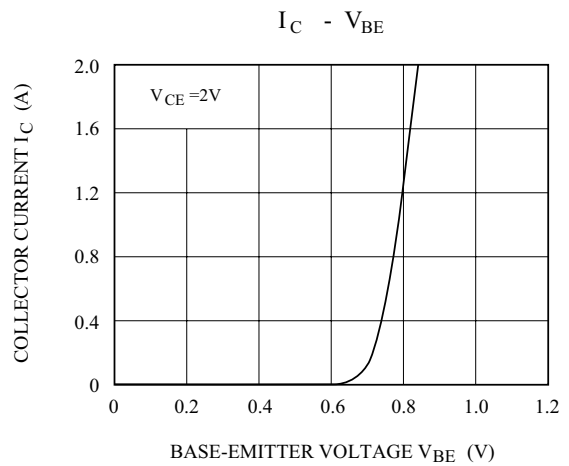
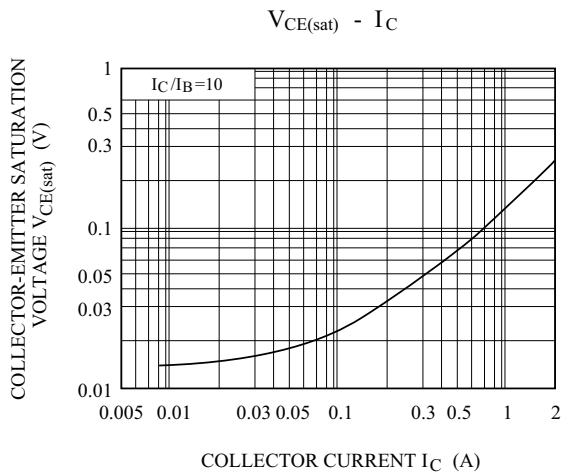
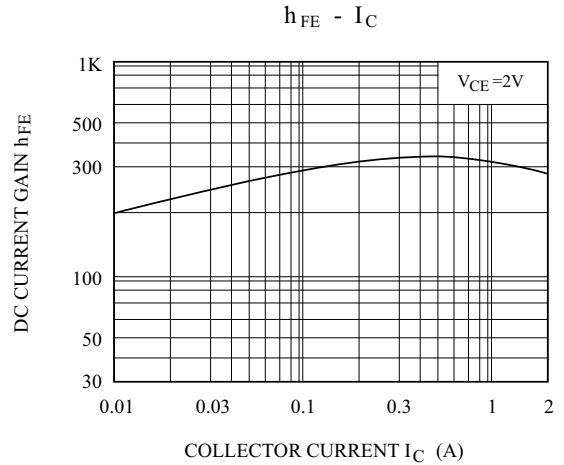
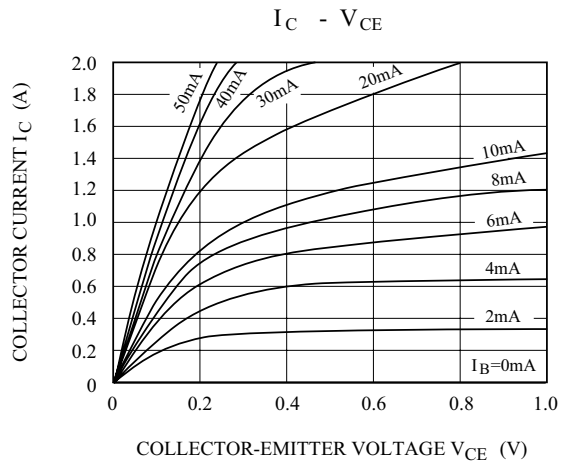


### ELECTRICAL CHARACTERISTICS (Ta=25 °C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB}=20V, I_E=0$	-	-	0.1	$\mu A$
Emitter Cut-off Current	$I_{EBO}$	$V_{EB}=3V, I_C=0$	-	-	0.1	$\mu A$
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu A, I_E=0$	30	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=1mA, I_B=0$	30	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=10\mu A, I_C=0$	6	-	-	V
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=1.5A, I_B=75mA$	-	180	400	mV
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=1.5A, I_B=75mA$	-	0.85	1.2	V
DC Current Gain	$h_{FE}$	$V_{CE}=2V, I_C=100mA$	200	-	560	
Transition Frequency	$f_T$	$V_{CE}=10V, I_C=50mA$	-	150	-	MHz
Collector Output Capacitance	$C_{ob}$	$V_{CB}=10V, f=1MHz$	-	19	-	pF
Switching Time	Turn-On Time	$t_{on}$	-	60	-	nS
	Storage Time	$t_{stg}$	-	500	-	
	Fall Time	$t_f$	-	25	-	

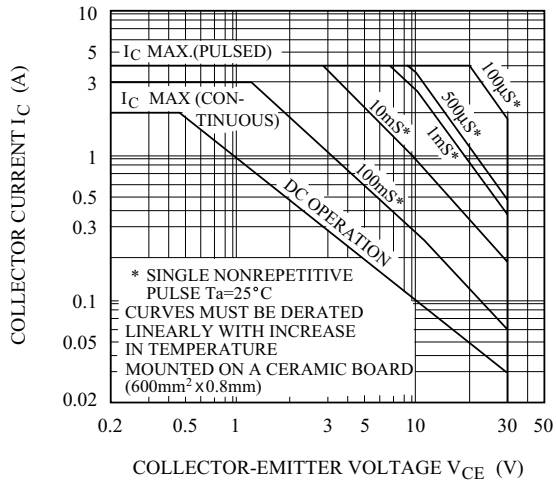
20I<sub>B1</sub>=20I<sub>B2</sub>=I<sub>C</sub>=500mA

# KTC3544T



# KTC3544T

SAFE OPERATING AREA



Pc - Ta

